ISOS141-SEP Production Flow and Reliability Report



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1 Trademarks

All trademarks are the property of their respective owners.



2 Texas Instruments Enhanced Product Qualification and Reliability Report

TI qualification testing is a risk mitigation process that is engineered to assure device longevity in customer applications. Wafer fabrication process and package level reliability are evaluated in a variety of ways that may include accelerated environmental test conditions with subsequent derating to actual use conditions. Manufacturability of the device is evaluated to verify a robust assembly flow and assure continuity of supply to customers, TI Enhanced Products are qualified with industry standard test methodologies performed to the intent of Joint Electron Devices Engineering Council (JEDEC) standards and procedures. Texas Instruments Enhanced Products are certified to meet GEIA-STD-0002-1 Aerospace Qualified Electronic Components.



3 Space Enhanced Plastic Production Flow

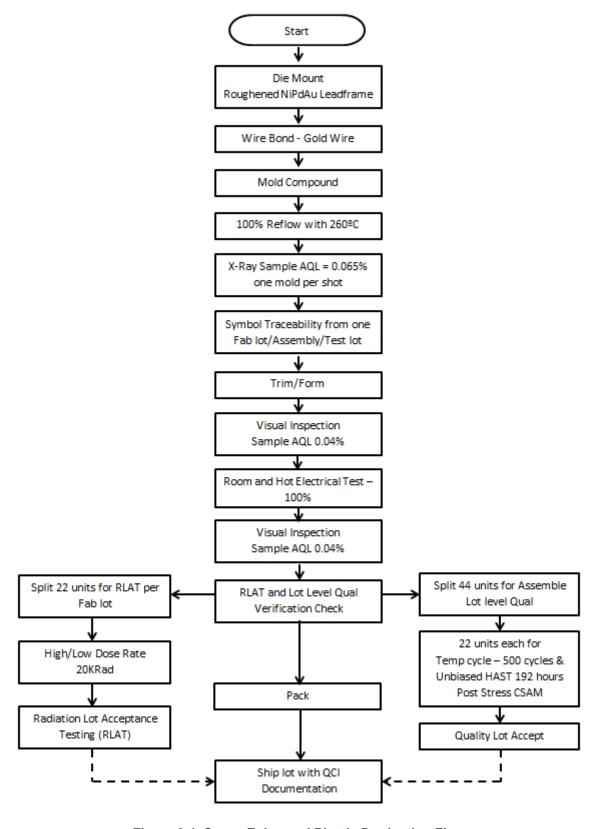


Figure 3-1. Space Enhanced Plastic Production Flow



4 Qualification by Similarity (Qualification Family)

A new device can be qualified either by performing full scale quality and reliability test on the actual device or using previously qualified device(s) through "Qualification by Similarity" (QBS) rules. By establishing similarity between the new device and those qualified previously, repetitive test will be eliminated, allowing for timely production release. When adopting QBS methodology, the emphasis is on qualifying the differences between a previously qualified product and the new product under consideration. The QBS rules for a technology, product, test parameter or package shall define which attributes are required to remain fixed in order for the QBS rules to apply. The attributes which are expected and allowed to vary will be reviewed and a QBS plan shall be developed, based on the reliability impact assessment above, specifying what subset of the full complement of environmental stresses is required to evaluate the reliability impact of those variations. Each new device shall be reviewed for the conformance to the QBS rule sets applicable to the device. See JEDEC JESD47 for more information.

Table 4-1. Device Baseline

TI Device:	ISOS141FDBQSEP	Assembly Site:	TI-TAI (Taiwan)
DLA VID:	V62/21610	Test Site:	TI-TAI (Taiwan)
Wafer Fab:	TIJ Miho8	Pin/Package Type:	QSOP (DBQ) 16
Fab Process:	LBC8LVISO	Leadframe:	Cu
Fab Technology:	BICMOS	Termination Finish:	NiPdAu
Die Revision:	A	Bond Wire:	24.3 µm Au
ESD CDM:	±1500V	Moisture Sensitivity:	MSL 2/ 260°C
ESD HBM:	±6000V		
1Baseline information	in effect as of the date of this report		

Table 4-2. Space Enhanced Products New Device Qualification Matrix

Note that qualification by similarity ("qualification family") per JEDEC JESD47 is allowed				
Description	Condition	Sample Size Used/ Rejects	Lots Required	Test Method
Electromigration	Maximum Recommended Operating Conditions	N/A	N/A	Per TI Design Rules
Wire Bond Life	Maximum Recommended Operating Conditions	N/A	N/A	Per TI Design Rules
Electrical Characterization	TI Data Sheet	10	3	N/A
Electrostatic Discharge Sensitivity	НВМ	3 units/voltage	1	EIA/JESD22-A114
	CDM			EIA/JESD22-C101
Latch-up	Per Technology	6/0	1	EIA/JESD78
Physical Dimensions	TI Data Sheet	5/0	1	EIA/JESD22- B100
Thermal Impedance	Theta-JA on board	Per Pin-Package	N/A	EIA/JESD51
Bias Life Test	125°C / 1000 hours or equivalent	77/0	3	JESD22-A108*
Biased HAST	130°C / 85% / 96 hours	77/0	3	JESD22-A110*
Extended Biased HAST	130°C / 85% / 250 hours (for reference)	77/0	1	JESD22-A110*
Unbiased HAST	130°C / 85% / 96 hours	77/0	3	JESD22-A110*
Temperature Cycle	-65°C to +150°C non- biased for 500 cycles	77/0	3	JESD22-A104*
Solder Heat	260°C for 10 seconds	22/0	1	JESD22-B106
Resistance to Solvents	Ink symbol only	12/0	1	JESD22-B107
Solderability	Condition A (steam age for 8 hours)	22/0	1	ANSI/J-STD-002-92
Flammability	Method A / Method B	5/0	1	UL-1964
Bond Shear	Per wire size	5 units x 30/0 bonds	3	JESD22-B116



Table 4-2. Space Enhanced Products New Device Qualification Matrix (continued)

	Sample Size Used/	Lata Bassirad	
	Rejects	Lots Required	Test Method
е	5 units x 30/0 bonds	3	ASTM F-459
	5/0	3	TM 2019
00 hours	15/0	3	JESD22-A103-A*
unt Only	12	1	J-STD-020-A*
ion Dose, and it Latchup	5 units/dose level	1	MIL-STD-883/Method 1019
Mass Lost), ected Volatile le material), r vapor	5	1	ASTM E595
r	ected Volatile e material), vapor	ected Volatile e material),	ected Volatile e material), vapor



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5 Outgas Test Report

Outgassing test was performed on 5 units. A total mass loss (TML) of 1.00% and collected volatile condensable material (CVCM) of 0.10% were used as screening levels for rejection of spacecraft materials. The outgas test was performed in a vacuum environment of less than 5×10 –5 torr according to ASTM E 595, for a duration of 24 hours, at 125°C. The TML, CVCM, and the amount of Water Vapor Recovered (WVR) were measured after the test.

Table 5-1. Outgas Test Results

SAMPLE	TML	CVCM	WVR
	(%)	(%)	(%)
ISOS141-SEP	0.07	<0.01	0.06

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